

### Features

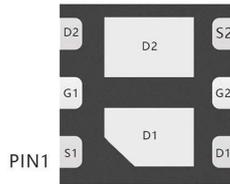
- Trench Power LV MOSFET technology
- High Density Cell Design for Low  $R_{DS(ON)}$
- High Speed switching

### Product Summary

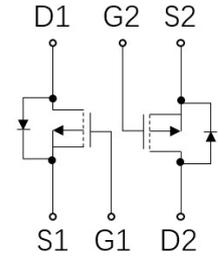
$V_{DS}$	$R_{DS(ON)}$ MAX	$I_D$ MAX
-30V	65mΩ@-10V	-4.5A
	100mΩ@-4.5V	

### Application

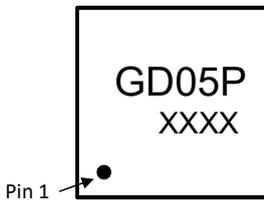
- Battery protection
- Load switch
- Power management



DFN2X2-6L view



Schematic diagram



Marking and pin assignment

GD05P: Device code  
 XXXX: Code  
 Solid dot: Pin1 indicator



Halogen-Free

### Absolute Maximum Ratings (TA=25°C unless otherwise noted)

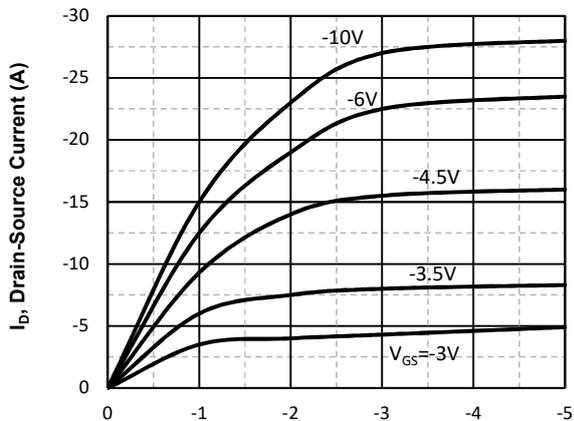
Symbol	Parameter	Rating	Unit
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>			
$V_{DS}$	Drain-Source Breakdown Voltage	-30	V
$V_{GS}$	Gate-Source Voltage	±20	V
$T_J$	Maximum Junction Temperature	150	°C
$T_{STG}$	Storage Temperature Range	-55 to 150	°C
$I_S$	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$ -4.5	A
<b>Mounted on Large Heat Sink</b>			
$I_{DM}$	Pulse Drain Current Tested	$T_c=25^\circ\text{C}$ -18	A
$I_D$	Continuous Drain Current	$T_c=25^\circ\text{C}$ -4.5	A
$P_D$	Maximum Power Dissipation	$T_c=25^\circ\text{C}$ 1.25	W
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient	85	°C/W

### Ordering Information (Example)

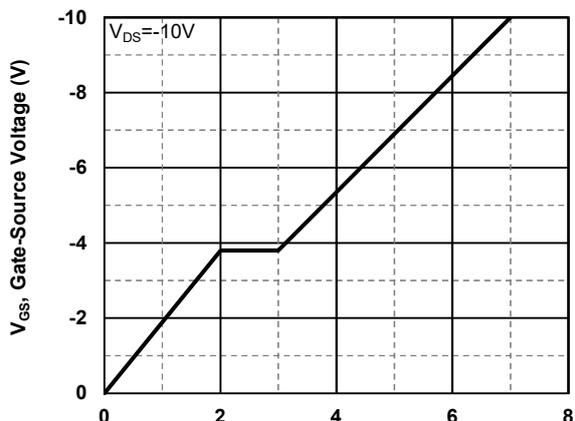
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLSMGD05P	DFN2X2-6L	GD05P	3,000	45,000	180,000	7"reel

Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-30	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	--	--	-1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.2	--	-2.2	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =-10V, I <sub>D</sub> =-4.5A	--	52	65	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-3.0A	--	77	100	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1MHz	--	260	--	pF
C <sub>OSS</sub>	Output Capacitance		--	50	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	40	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =-15V, I <sub>D</sub> =-3A, V <sub>GS</sub> =-10V	--	7	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	2	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	1	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =-15V, I <sub>D</sub> =-3A, V <sub>GS</sub> =-4.5V, R <sub>G</sub> =3Ω	--	5	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	23	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	21	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	30	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =-4.5A	--	--	-1.2	V

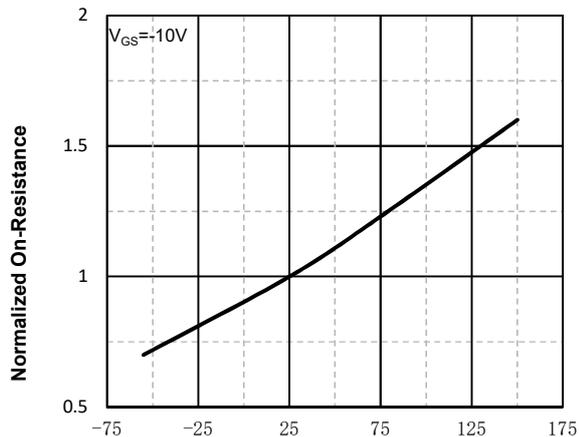
Typical Operating Characteristics



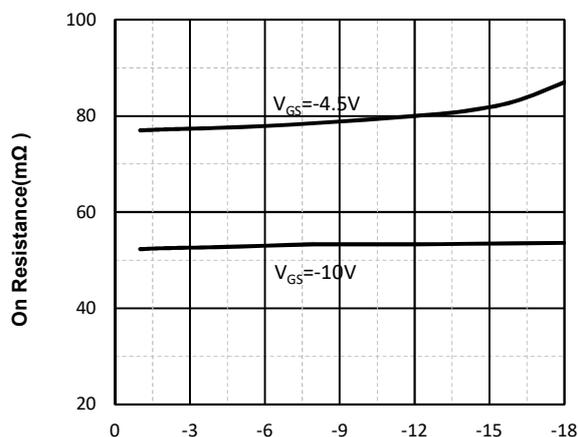
$V_{DS}$ , Drain-Source Voltage (V)  
Fig1. Typical Output Characteristics



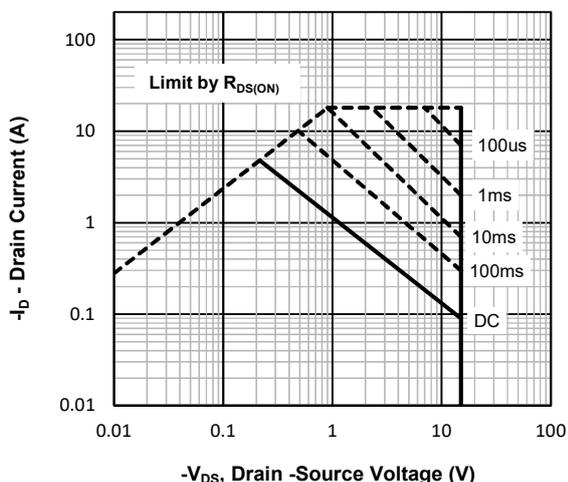
Qg -Total Gate Charge (nC)  
Fig2. Typical Gate Charge Vs. Gate-Source Voltage



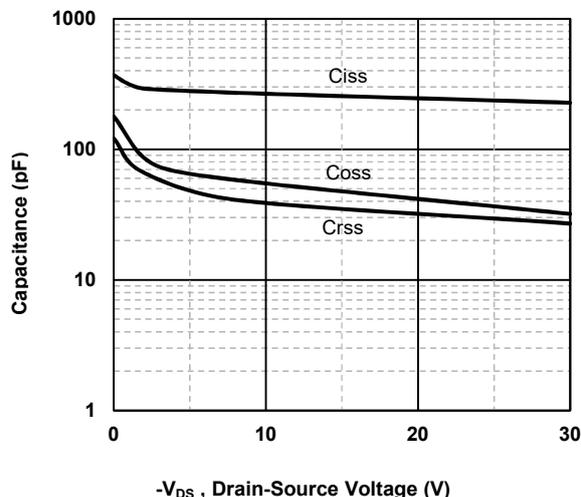
$T_j$  - Junction Temperature ( $^{\circ}C$ )  
Fig3. Normalized On-Resistance Vs. Temperature



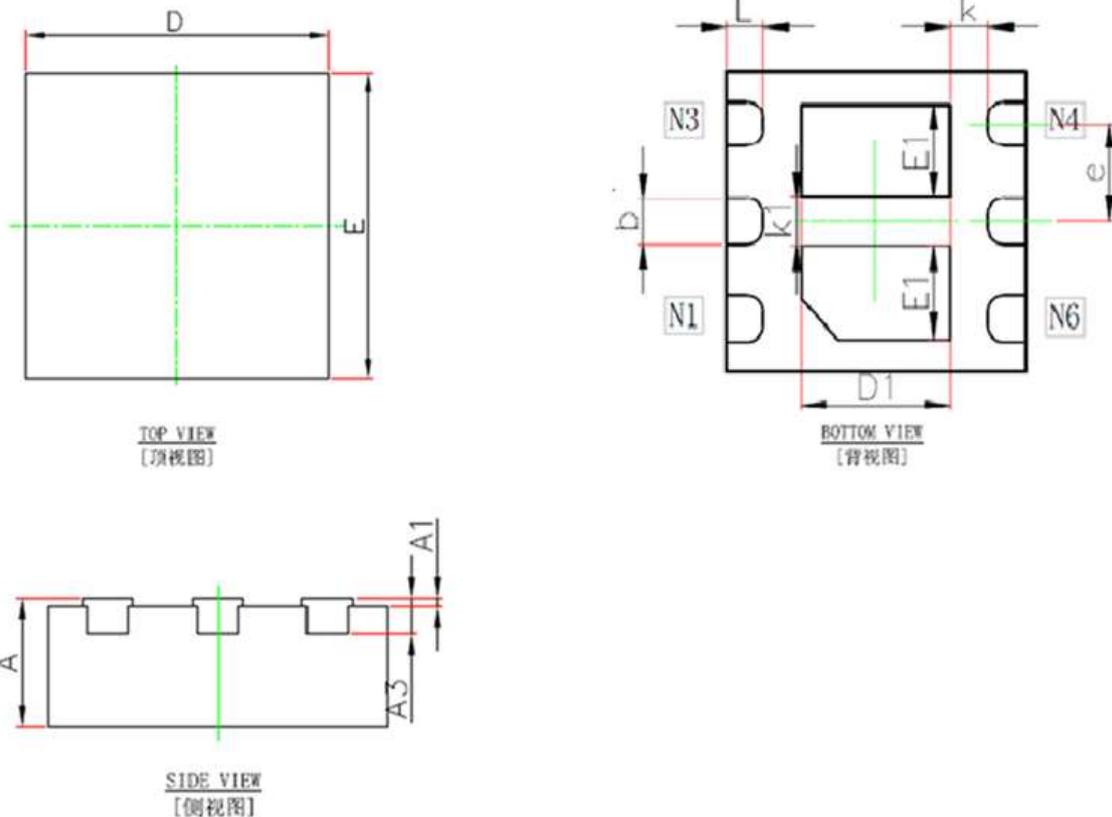
$I_D$ , Drain-Source Current (A)  
Fig4. On Resistance Vs. Drain-Source Current



$-V_{DS}$ , Drain-Source Voltage (V)  
Fig5. Maximum Safe Operating Area



$-V_{DS}$ , Drain-Source Voltage (V)  
Fig6 Typical Capacitance Vs. Drain-Source Voltage

**DFN2X2-6L Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.600	0.700	0.024	0.027
A1	0.000	0.050	0.000	0.001
A3	0.203REF		0.007REF	
b	0.230	0.330	0.009	0.012
D	1.924	2.076	0.075	0.081
E	1.924	2.076	0.075	0.081
e	0.650TYP		0.025TYP	
L	0.224	0.376	0.008	0.014
k	0.200	-	0.007	-
E1	0.520	0.720	0.020	0.028
D1	0.800	1.000	0.031	0.039
K1	0.320TYP		0.012TYP	